

## **PMPB14XNX** Datasheet

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PMPB14XNX-DG
Nexperia USA Inc.
PMPB14XNX
MOSFET N-CH 40V 8.1A DFN2020MD-6
N-Channel 40 V 8.1A (Ta) 3.8W (Ta), 12.5W (Tc) Sur face Mount DFN2020MD-6

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## Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PMPB14XNX	Nexperia USA Inc.
Series:	Product Status:
TrenchMOS™	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
40 V	8.1A (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
1.5V, 4.5V	18mOhm @ 8.1A, 4.5V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
900mV @ 250µA	28 nC @ 4.5 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±8V	1625 pF @ 20 V
FET Feature:	Power Dissipation (Max):
	3.8W (Ta), 12.5W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
DFN2020MD-6	6-UDFN Exposed Pad
Base Product Number:	
PMPB14	

## **Environmental & Export classification**

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0095	



# PMPB14XN 40 V, N-channel Trench MOSFET 11 March 2020

**Product data sheet** 

## 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

## 2. Features and benefits

- Very fast switching
- Low threshold voltage
- Trench MOSFET technology •
- Side wettable flanks for optical solder inspection
- Exposed drain pad for excellent thermal conduction

## 3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	40	V
V <sub>GS</sub>	gate-source voltage	_		-8	-	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-	11.5	А
Static chara	cteristics						
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 8.1 A; T <sub>j</sub> = 25 °C		-	15	18	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

## nexperia

## 5. Pinning information

Table 2	. Pinning info	ormation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G-UFTA
4	S	source	3 8 4	s s
5	D	drain	Transparent top view	017aaa253
6	D	drain	DFN2020MD-6 (SOT1220)	
7	D	drain		
8	S	source		

## 6. Ordering information

#### Table 3. Ordering information

Type number	Package	'ackage					
	Name	Description	Version				
PMPB14XN		plastic, leadless thermal enhanced ultra thin small outline package with side-wettable flanks (SWF); 6 terminals; 0.65 mm pitch; 2 mm x 2 mm x 0.65 mm body	SOT1220				

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PMPB14XN	5D

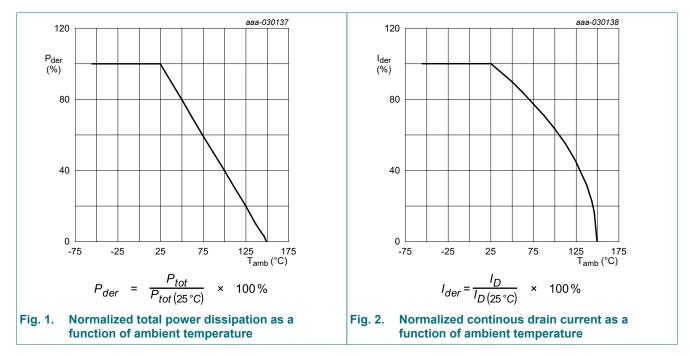
## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

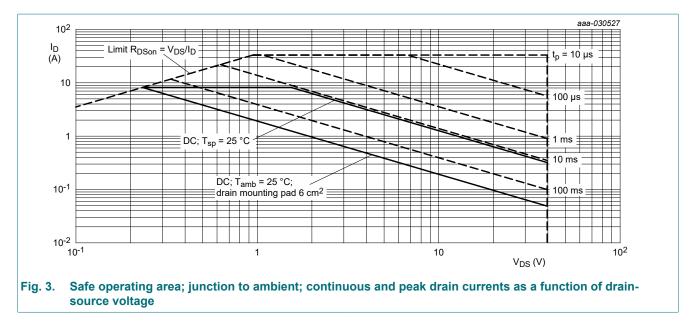
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	40	V
V <sub>GS</sub>	gate-source voltage	_		-8	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	11.5	А
		V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	8.1	А
		V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	5.1	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	33	А
P <sub>tot</sub> total power dissipation	T <sub>amb</sub> = 25 °C	[1]	-	1.9	W	
		T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	3.8	W
		T <sub>sp</sub> = 25 °C		-	12.5	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drai	n diode					
ls	source current	T <sub>amb</sub> = 25 °C	[1]	-	1.9	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



## PMPB14XN

#### 40 V, N-channel Trench MOSFET



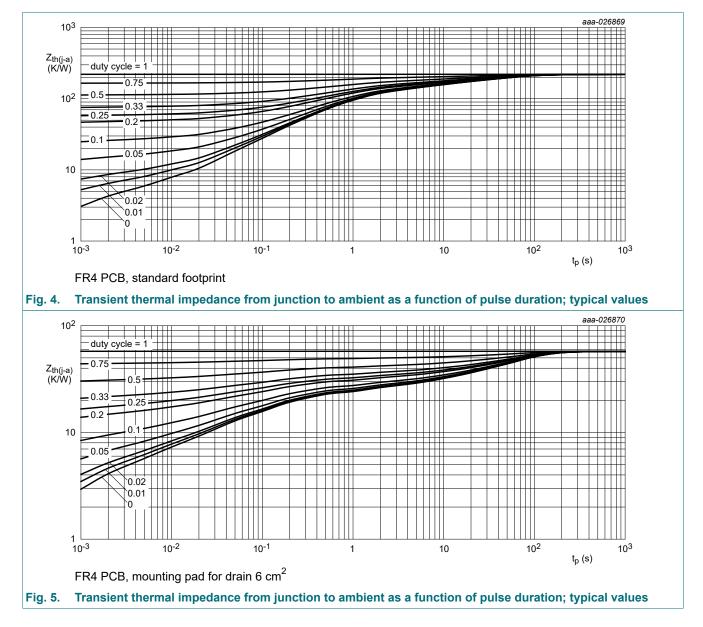
PMPB14XN

## 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R <sub>th(j-a)</sub> thermal resistance from junction to ambient	in free air	[1]	-	223	256	K/W	
		[2]	-	57	66	K/W	
	in free air; t ≤ 5 s	[2]	-	29	33	K/W	
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	6	10	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

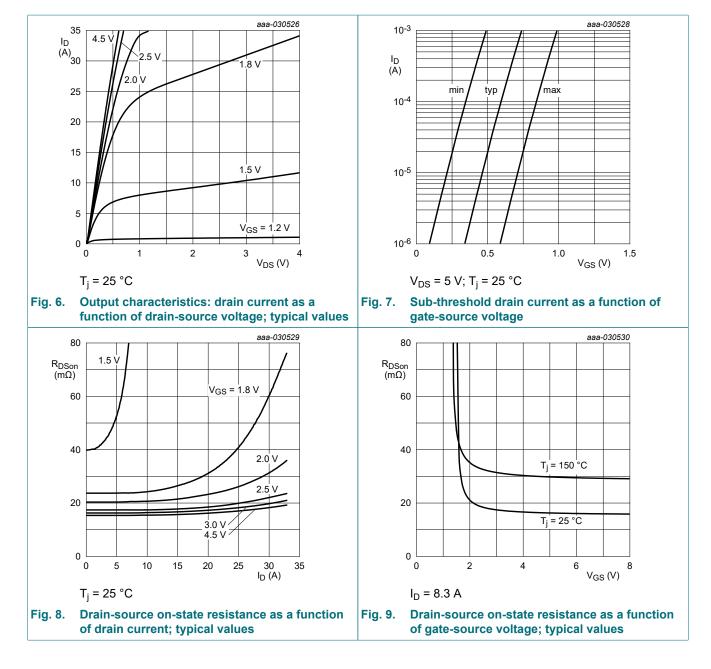


## **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	40	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	I <sub>D</sub> = 250 μA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 25 °C	0.4	0.65	0.9	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 40 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = -8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-100	nA
		V <sub>GS</sub> = 8 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	100	nA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 8.1 A; T <sub>j</sub> = 25 °C	-	15	18	mΩ
	resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 8.1 A; T <sub>j</sub> = 150 °C	-	24	29	mΩ
	V <sub>GS</sub> = 2.5 V; I <sub>D</sub> = 7.3 A; T <sub>j</sub> = 25 °C	-	17	22	mΩ	
		V <sub>GS</sub> = 1.8 V; I <sub>D</sub> = 3 A; T <sub>j</sub> = 25 °C	-	23	32	mΩ
		V <sub>GS</sub> = 1.5 V; I <sub>D</sub> = 0.5 A; T <sub>j</sub> = 25 °C	-	40	100	mΩ
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 8.3 A; T <sub>j</sub> = 25 °C	-	22	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	2.4	-	Ω
Dynamic ch	aracteristics	1	I			
Q <sub>G(tot)</sub>	total gate charge	V <sub>DS</sub> = 20 V; I <sub>D</sub> = 8.3 A; V <sub>GS</sub> = 4.5 V;	-	19.4	28	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	2.4	-	nC
Q <sub>GD</sub>	gate-drain charge	1	-	5.6	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 20 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	1625	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	99	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	85	-	pF
t <sub>d(on)</sub>	turn-on delay time	V <sub>DS</sub> = 20 V; I <sub>D</sub> = 8.3 A; V <sub>GS</sub> = 4.5 V;	-	5	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	8	-	ns
t <sub>d(off)</sub>	turn-off delay time	1 [	-	35	-	ns
t <sub>f</sub>	fall time	1	-	15	-	ns
Source-drai	n diode			1		
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 1.9 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	0.7	1.2	V

## PMPB14XN

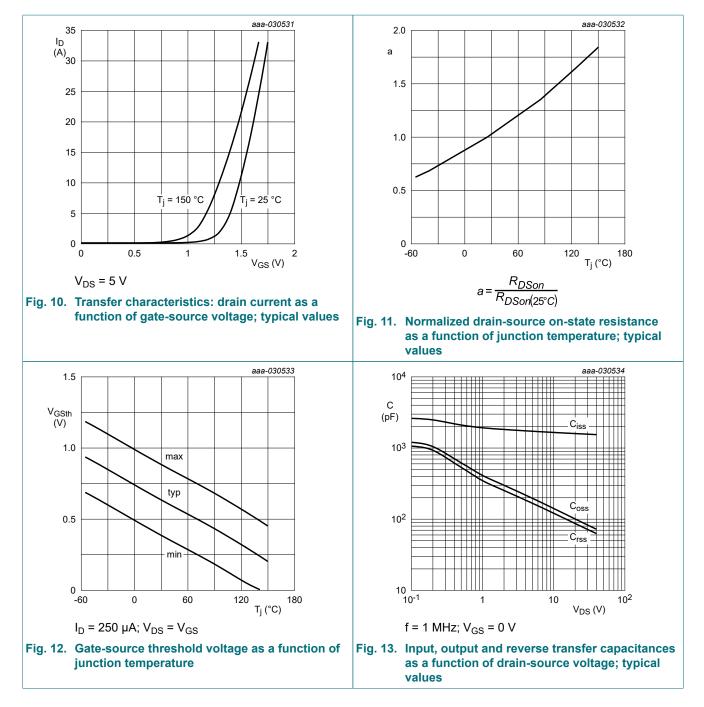
#### 40 V, N-channel Trench MOSFET



**Product data sheet** 

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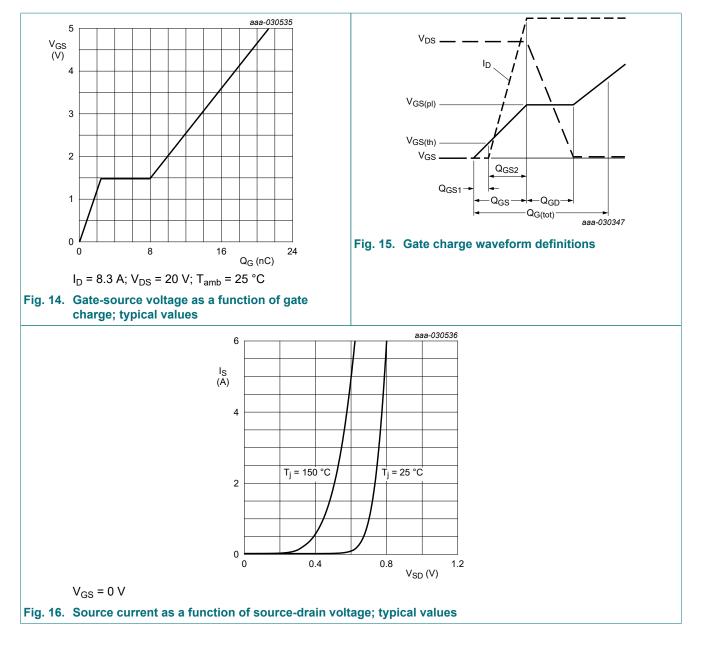
#### 40 V, N-channel Trench MOSFET



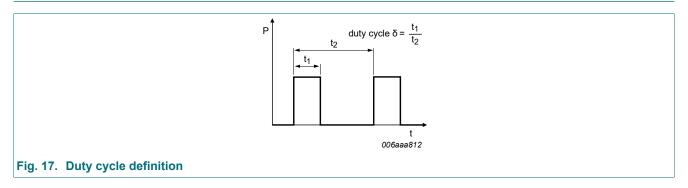
**Product data sheet** 

## PMPB14XN

#### 40 V, N-channel Trench MOSFET



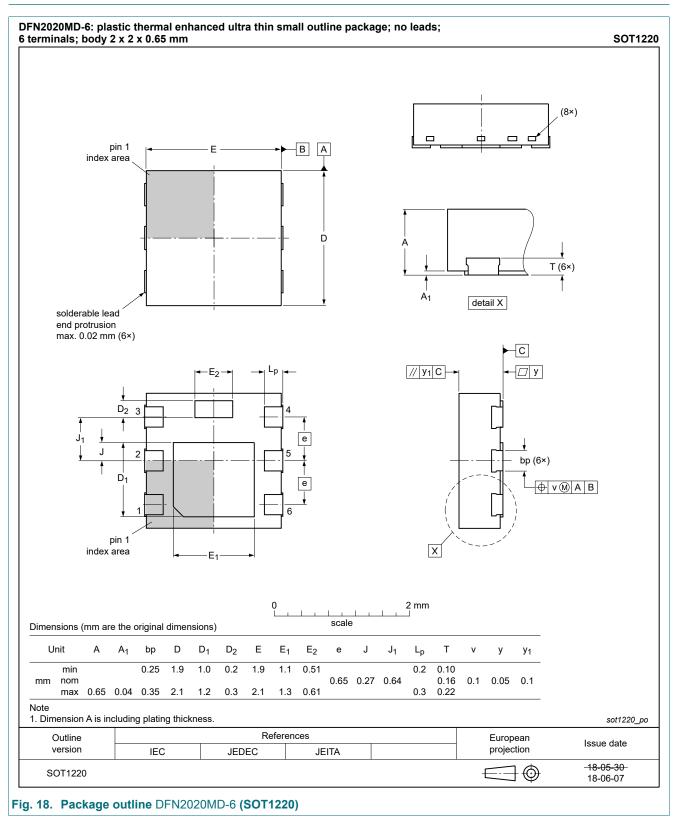
## 11. Test information



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## PMPB14XN

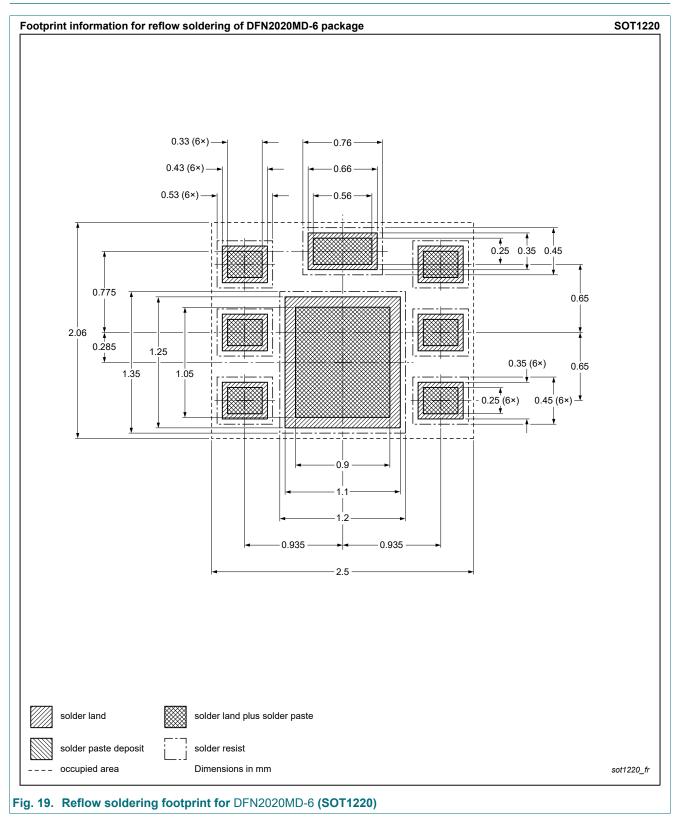
## 12. Package outline



## PMPB14XN

#### 40 V, N-channel Trench MOSFET

## 13. Soldering



## 14. Revision history

Table 8. Revision histor	ry			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMPB14XN v.1	20200311	Product data sheet	-	-

PMPB14XN

## PMPB14XN

#### 40 V, N-channel Trench MOSFET

## 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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## PMPB14XN

#### 40 V, N-channel Trench MOSFET

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